## NSN 5962-01-260-8681

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View Online at https://aerobasegroup.com/nsn/5962-01-260-8681 **Body Length:** 0.560 inches **Body Width:** 0.458 inches **Body Height:** 0.120 inches **Maximum Power Dissipation Rating:** 1.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and static operation **Inclosure Material:** Ceramic **Inclosure Configuration:** Leadless flat pack **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 21 input **Case Outline Source And Designator:** C-12 mil-m-38510 **Current Rating Per Characteristic:** 125.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Memory Device Type:** Ram **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 32 gullwing Shelf Life: N/a **Unit Of Measure:** 

No

**Demilitarization:** 

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